

isc N-Channel MOSFET Transistor

STD8NM50N

 Drain So : V_{DSS}= 5 Static Dr : R_{DS(on)} = 100% av Minimum performa 	irrent $-I_D$ = 5A@ T _C =25°C urce Voltage- i00V(Min) ain-Source On-Resistance = 790m Ω (Max) alanche tested in Lot-to-Lot variations for robust device unce and reliable operation	DPAK DPAK DPAK C 0.5 C 0		
	E MAXIMUM RATINGS(Ta=25°C)			
SYMBOL	PARAMETER	VALUE		D
V _{DSS}	Drain-Source Voltage	500	V	
V _{GS}	Gate-Source Voltage-Continuous	±25	V	
ID	Drain Current-Continuous	5	A	F F F F F
PD	Total Dissipation @T _C =25℃	45	W	G
TJ	Max. Operating Junction Temperature	150	°C	mm
T _{stg}	Storage Temperature	-55~150	°C	DIM MIN MAX A 6.40 6.60 B 5.20 5.40
THERMAL	CHARACTERISTICS			C 1.15 1.35 D 5.70 6.10 F 0.65 G 0.75
SYMBOL	PARAMETER	МАХ	UNIT	H 2.10 2.50 J 2.10 2.40
Rth j-c	Thermal Resistance, Junction to Case	2.78	°C/W	K 0.40 0.60 L 0.90 1.10 Q 9.90 10.1



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	500		V
V _{GS} (th)	Gate Threshold Voltage	V_{DS} = V_{GS} ; I_D = 0.25mA	2	4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 2.5A		790	mΩ
lgss	Gate-Body Leakage Current	V _{GS} = ±25V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = Max rating; V _{DS} = Max rating; T _j = 125°C		1 100	μA
V _{SD}	Forward On-Voltage	I _S = 5A; V _{GS} =0		1.5	V

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